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Electronic transmission through the atomic domain boundary

--- from graphene to transition metal dichalcogenides

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Family of 2D materials

Graphene



hexagonal BN





Transition metal dichalcogenides (TMD)

Phosphorene



MX₂ (M=Mo,W; X=S, Se,Te)





Nature Nanotechnology 9, 330-331 (2014) DOI: 10.1038/nnano.2014.85

Spintronics in 2D materials?



··· Can we do this in better way in 2D materials ?

Graphene



Monolayer

Bilayer (AB-stacked)

Graphene



Graphene atomic boundary splits valley pseudo-spins (K,K')

Transition metal dichalcogenides (TMD)

MX₂ (M=Mo,W; X=S, Se,Te)



Monolayer

Bilayer

Transition metal dichalcogenides (TMD)

MX₂ (M=Mo,W; X=S, Se,Te)



TMD atomic boundary splits real spins!

TMD monolayer-bilayer junction works as a spin splitter



T. Habe and M. Koshino, Phys. Rev. B 91, 201407(R) (2015)

Graphene's band structure



Graphene monolayer-bilayer junction

Theoretical studies

Nakanishi, Koshino, Ando, PRB **82**, 125428 (2010) Koshino, Nakanishi, Ando PRB **82**, 205436 (2010)





Experiments



0L 1L 2L Conductance (ms) (b) 0.33 0.33 0.000 0.00

Tsukada et al, J. Phys.: Conf. Series 334,012038 (2011)

Giannazzo et al, Phys. Rev. B 86, 235422 (2012)

Boundary condition in continuum model

Monolayer (K-valley)Hamiltonian $\mathcal{H}^{K} = \begin{pmatrix} 0 & vp_{-} \\ vp_{+} & 0 \end{pmatrix}$
 $p_{\pm} = p_{x} \pm ip_{y}$ Wavefunction $\mathbf{F}^{K}(\mathbf{r}) = \begin{pmatrix} F_{A}^{K}(\mathbf{r}) \\ F_{R}^{K}(\mathbf{r}) \end{pmatrix}$

$$\begin{aligned} \mathbf{Bilayer} & (\mathbf{K}\text{-valley}) \\ \mathcal{H}^{K} = \begin{pmatrix} 0 & vp_{-} & 0 & 0 \\ vp_{+} & 0 & \gamma_{1} & 0 \\ 0 & \gamma_{1} & 0 & vp_{-} \\ 0 & 0 & vp_{+} & 0 \end{pmatrix} \\ \mathbf{G}^{K}_{A1}(\mathbf{r}) \\ G^{K}_{B1}(\mathbf{r}) \\ G^{K}_{A2}(\mathbf{r}) \\ G^{K}_{B2}(\mathbf{r}) \end{pmatrix} \end{aligned}$$

Boundary condition (Zigzag-1)

$$\left. \begin{array}{l} F_A^K(0,y) = G_{A1}^K(0,y) \\ F_B^K(0,y) = G_{B1}^K(0,y) \end{array} \right] \ \ 1 \text{st layer} \\ 0 = G_{B2}^K(0,y) - \text{2nd layer} \end{array}$$



Transmission through M-B junction

T. Nakanishi, MK, T. Ando PRB **82**, 125428 (2010)



Transmission Probability (K-valley)



Transmission through M-B junction

T. Nakanishi, MK, T. Ando PRB **82**, 125428 (2010)



Why angle-asymmetric?



Mirror symmetry \cdots Transmission should be symmetric with respect to q = 0?

Why angle-asymmetric?



Graphene



Graphene atomic boundary splits valley pseudo-spins (K,K')

Valley-polarizing mechanism

T. Nakanishi, MK, T. Ando PRB **82**, 125428 (2010)



Monolayer



Valley polarization

AB-BA domain in bilayer graphene

J. S. Alden et al, PNAS 110, 11256 (2013)

BA







AB





BA



Valley polarization

M. Koshino, Phys. Rev. B 88, 115409 (2013)

Reflection symmetry: K and K' have opposite angle dependence



TMD (Transition metal dichalcogenides)



K. F. Mak, et al, Nat. Nano. 7, 494 (2012), D. Xiao, et al, PRL 108, 196802 (2012).

TMD (Transition metal dichalcogenides)



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TMD atomic junciton

T. Habe and M. Koshino, Phys. Rev. B 91, 201407(R) (2015)



Theoretical Method



ii) Create tight-binding model (Wannier 90)



iii) Calculate the transmission probability





Electron transmission: MoTe₂

```
[hole-doped;
n=-7.02x10<sup>13</sup> cm<sup>-2</sup>]
```



spin ↑



Transmission is highly angle-selective





Electron transmission: MoTe₂

```
[hole-doped;
n=-7.02x10<sup>13</sup> cm<sup>-2</sup>]
```



spin ↑

spin↓

Collimated to different directions depending on spin!





Mechanism of spin-dependent transmission



···· Larger Fermi circle in monolayer than in bilayer



Other TMDs



Г

Spin splitter



Cf. spin splitters proposed in conventional 2DEG (Rashba spin-orbit interaction)



··· Spin is not a conserved quantity under impurity scattering

Summary

- --- Atomic boundary in 2D material causes flavor-dependent electron transmission
- --- Graphene mono-bi junction splits valley pseudospins
- --- TMD (MoSe₂, MoTe₂, WSe₂, WTe₂) mono-bi junction splits real spins
- --- Possible application to spin-filtering devices

Acknowlegements

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T. Nakanishi, M. Koshino, T. Ando PRB **82**, 125428 (2010)



T. Habe and M. Koshino, Phys. Rev. B 91, 201407(R) (2015)

Dependence on edge configuration

T. Nakanishi, MK, T. Ando PRB **82**, 125428 (2010)

